

# 74VHC164FT

## 1. Functional Description

- 8-Bit Shift Register (S-IN, P-OUT)

## 2. General

The 74VHC164FT is an advanced high speed CMOS 8-BIT SERIAL-IN PARALLEL-OUT SHIFT REGISTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of serial-in, parallel-out 8-bit shift register with a CLOCK input and an overriding  $\overline{\text{CLEAR}}$  input.

Two serial data inputs (A, B) are provided so that one may be used as a data enable.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3 V systems and two supply systems such as battery back up.

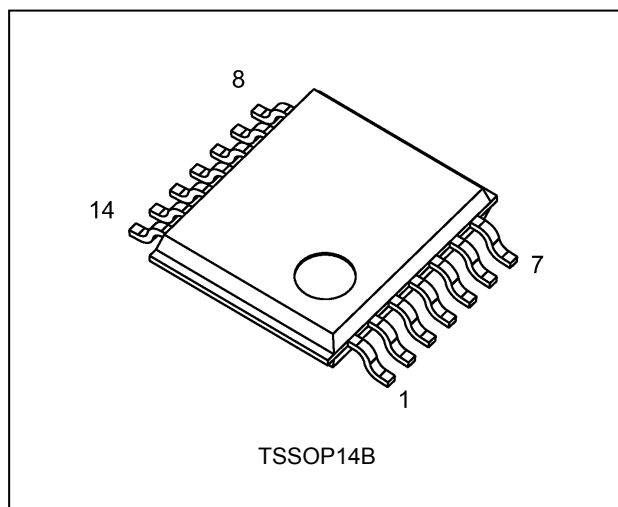
This circuit prevents device destruction due to mismatched supply and input voltages.

## 3. Features

- (1) AEC-Q100 (Grade 1) qualified (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to  $125$  °C
- (3) High speed:  $f_{MAX} = 175$  MHz (typ.) at  $V_{CC} = 5$  V
- (4) Low power dissipation:  $I_{CC} = 4$   $\mu$ A (max) at  $T_a = 25$  °C
- (5) High noise immunity:  $V_{NIH} = V_{NIL} = 28$  %  $V_{CC}$  (min)
- (6) Power-down protection is provided on all inputs.
- (7) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (8) Wide operating voltage range:  $V_{CC(opr)} = 2$  V to  $5.5$  V
- (9) Low noise:  $V_{OLP} = 0.8$  V (max)
- (10) Pin and function compatible with the 74 series (AC/HC/AHC etc.) 164 type.

Note 1: For detail information, please contact to our sales.

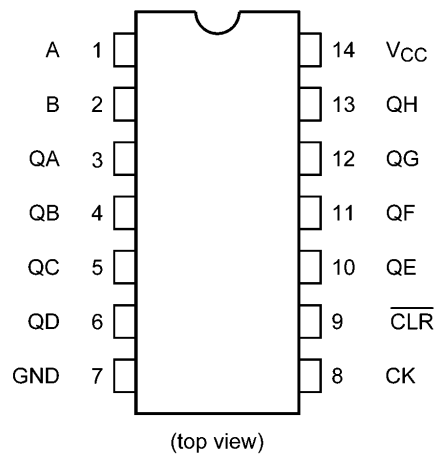
## 4. Packaging



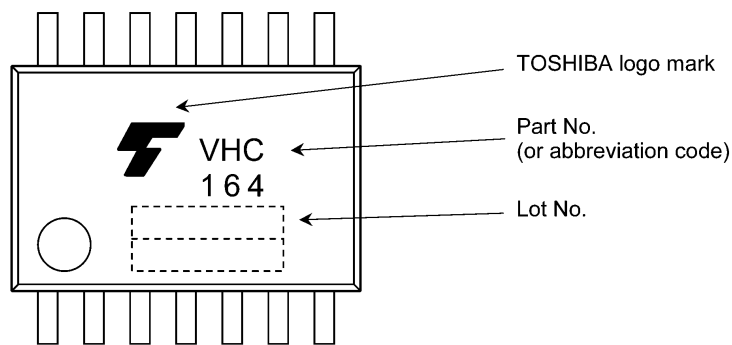
Start of commercial production

2013-05

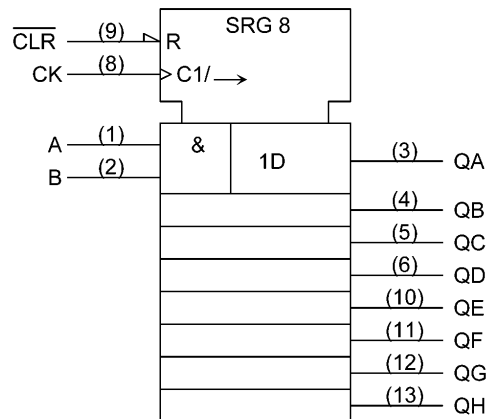
**5. Pin Assignment**







**6. Marking**



**7. IEC Logic Symbol**



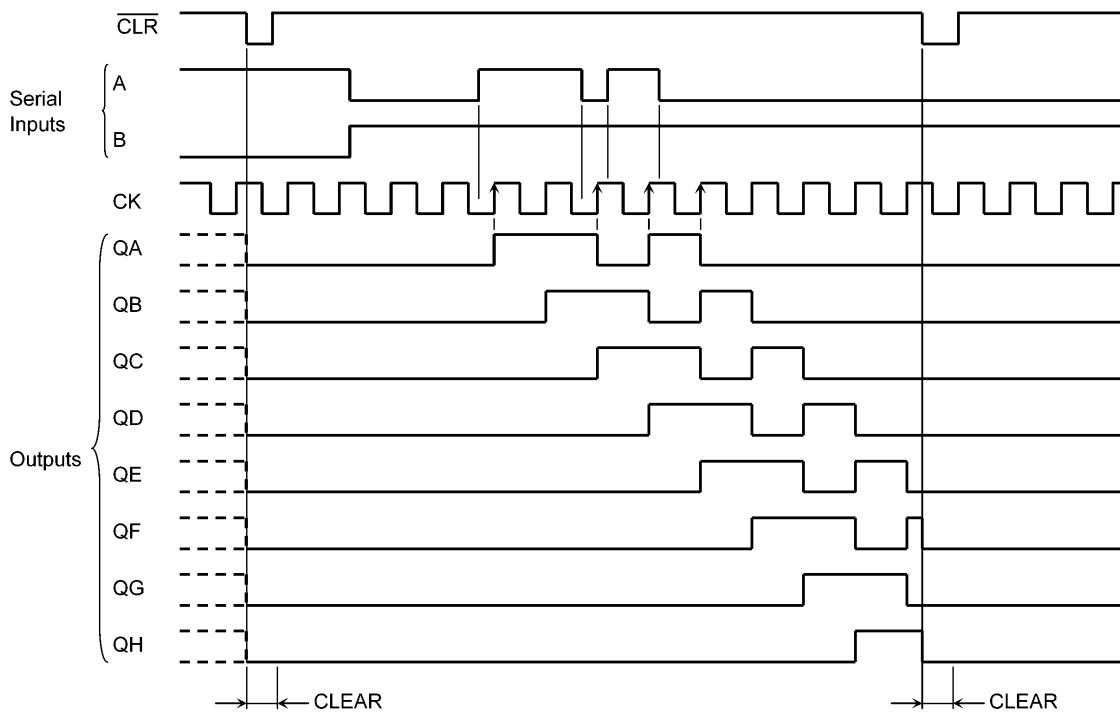
**8. Truth Table**

Inputs				Outputs			
$\overline{\text{CLR}}$	CK	Serial IN		QA	QB	...	QH
		A	B				
L	X	X	X	L	L	...	L
H		X	X	No Change			
H		L	X	L	QA <sub>n</sub>	...	QG <sub>n</sub>
H		X	L	L	QA <sub>n</sub>	...	QG <sub>n</sub>
H		H	H	H	QA <sub>n</sub>	...	QG <sub>n</sub>

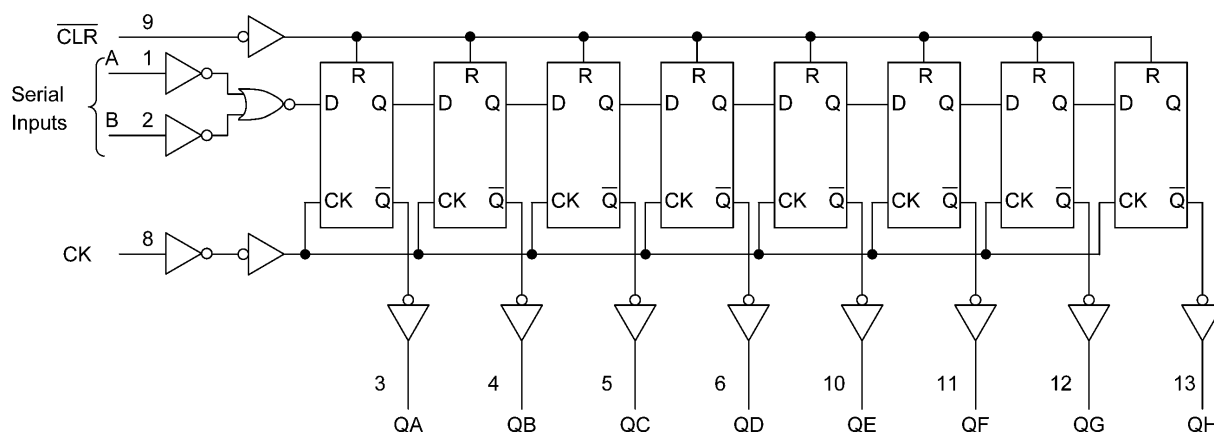
X: Don't care

QA<sub>n</sub> to QG<sub>n</sub>: The level of QA to QG, respectively, before the most recent positive edge of the CK.

**9. Timing Diagrams**



### 10. System Diagram



### 11. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	$V_{CC}$		-0.5 to 7.0	V
Input voltage	$V_{IN}$		-0.5 to 7.0	V
Output voltage	$V_{OUT}$		-0.5 to $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$		-20	mA
Output diode current	$I_{OK}$		$\pm 20$	mA
Output current	$I_{OUT}$		$\pm 25$	mA
$V_{CC}$ /ground current	$I_{CC}$		$\pm 75$	mA
Power dissipation	$P_D$	(Note 1)	180	mW
Storage temperature	$T_{stg}$		-65 to 150	$^{\circ}C$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a = -40$  to  $85^{\circ}C$ . From  $T_a = 85$  to  $125^{\circ}C$  a derating factor of  $-3.25$  mW/ $^{\circ}C$  shall be applied until 50 mW.

### 12. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	$V_{CC}$		2.0 to 5.5	V
Input voltage	$V_{IN}$		0 to 5.5	V
Output voltage	$V_{OUT}$		0 to $V_{CC}$	V
Operating temperature	$T_{opr}$		-40 to 125	$^{\circ}C$
Input rise and fall times	dt/dv	$V_{CC} = 3.3 \pm 0.3$ V	0 to 100	ns/V
		$V_{CC} = 5 \pm 0.5$ V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

**13. Electrical Characteristics**

**13.1. DC Characteristics (Unless otherwise specified,  $T_a = 25\text{ }^\circ\text{C}$ )**

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Min	Typ.	Max	Unit	
High-level input voltage	$V_{IH}$	—	2.0	1.50	—	—	V	
			3.0 to 5.5	$V_{CC} \times 0.7$	—	—		
Low-level input voltage	$V_{IL}$	—	2.0	—	—	0.50	V	
			3.0 to 5.5	—	—	$V_{CC} \times 0.3$		
High-level output voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50\text{ }\mu\text{A}$	2.0	1.9	2.0	—	V
				3.0	2.9	3.0	—	
				4.5	4.4	4.5	—	
			$I_{OH} = -4\text{ mA}$	3.0	2.58	—	—	
			$I_{OH} = -8\text{ mA}$	4.5	3.94	—	—	
Low-level output voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50\text{ }\mu\text{A}$	2.0	—	0.0	0.1	V
				3.0	—	0.0	0.1	
				4.5	—	0.0	0.1	
			$I_{OL} = 4\text{ mA}$	3.0	—	—	0.36	
			$I_{OL} = 8\text{ mA}$	4.5	—	—	0.36	
Input leakage current	$I_{IN}$	$V_{IN} = 5.5\text{ V}$ or GND	0 to 5.5	—	—	$\pm 0.1$	$\mu\text{A}$	
Quiescent supply current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	4.0	$\mu\text{A}$	

**13.2. DC Characteristics (Unless otherwise specified,  $T_a = -40$  to  $85\text{ }^\circ\text{C}$ )**

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Min	Max	Unit	
High-level input voltage	$V_{IH}$	—	2.0	1.50	—	V	
			3.0 to 5.5	$V_{CC} \times 0.7$	—		
Low-level input voltage	$V_{IL}$	—	2.0	—	0.50	V	
			3.0 to 5.5	—	$V_{CC} \times 0.3$		
High-level output voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50\text{ }\mu\text{A}$	2.0	1.9	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			$I_{OH} = -4\text{ mA}$	3.0	2.48	—	
			$I_{OH} = -8\text{ mA}$	4.5	3.80	—	
Low-level output voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50\text{ }\mu\text{A}$	2.0	—	0.1	V
				3.0	—	0.1	
				4.5	—	0.1	
			$I_{OL} = 4\text{ mA}$	3.0	—	0.44	
			$I_{OL} = 8\text{ mA}$	4.5	—	0.44	
Input leakage current	$I_{IN}$	$V_{IN} = 5.5\text{ V}$ or GND	0 to 5.5	—	$\pm 1.0$	$\mu\text{A}$	
Quiescent supply current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	40.0	$\mu\text{A}$	

**13.3. DC Characteristics (Unless otherwise specified,  $T_a = -40$  to  $125$  °C)**

Characteristics	Symbol	Test Condition		$V_{CC}$ (V)	Min	Max	Unit
High-level input voltage	$V_{IH}$	—		2.0	1.50	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	—	
Low-level input voltage	$V_{IL}$	—		2.0	—	0.50	V
				3.0 to 5.5	—	$V_{CC} \times 0.3$	
High-level output voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50 \mu A$	2.0	1.9	—	V
				3.0	2.9	—	
				4.5	4.4	—	
				$I_{OH} = -4$ mA	3.0	2.40	
Low-level output voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50 \mu A$	2.0	—	0.1	V
				3.0	—	0.1	
				4.5	—	0.1	
				$I_{OL} = 4$ mA	3.0	—	
Input leakage current	$I_{IN}$	$V_{IN} = 5.5$ V or GND		0 to 5.5	—	$\pm 2.0$	$\mu A$
				5.5	—	80.0	
Quiescent supply current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND		5.5	—	80.0	$\mu A$

**13.4. Timing Requirements (Unless otherwise specified,  $T_a = 25$  °C, Input:  $t_r = t_f = 3$  ns)**

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	—	$3.3 \pm 0.3$	5.0	ns
			$5.0 \pm 0.5$	5.0	
Minimum pulse width ( $\overline{CLR}$ )	$t_{w(L)}$	—	$3.3 \pm 0.3$	5.0	ns
			$5.0 \pm 0.5$	5.0	
Minimum setup time	$t_s$	—	$3.3 \pm 0.3$	5.0	ns
			$5.0 \pm 0.5$	4.5	
Minimum hold time	$t_h$	—	$3.3 \pm 0.3$	0.0	ns
			$5.0 \pm 0.5$	1.0	
Minimum removal time ( $\overline{CLR}$ )	$t_{rem}$	—	$3.3 \pm 0.3$	2.5	ns
			$5.0 \pm 0.5$	2.5	

**13.5. Timing Requirements (Unless otherwise specified,  $T_a = -40$  to  $85$  °C, Input:  $t_r = t_f = 3$  ns)**

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	—	$3.3 \pm 0.3$	5.0	ns
			$5.0 \pm 0.5$	5.0	
Minimum pulse width ( $\overline{CLR}$ )	$t_{w(L)}$	—	$3.3 \pm 0.3$	5.0	ns
			$5.0 \pm 0.5$	5.0	
Minimum setup time	$t_s$	—	$3.3 \pm 0.3$	6.0	ns
			$5.0 \pm 0.5$	4.5	
Minimum hold time	$t_h$	—	$3.3 \pm 0.3$	0.0	ns
			$5.0 \pm 0.5$	1.0	
Minimum removal time ( $\overline{CLR}$ )	$t_{rem}$	—	$3.3 \pm 0.3$	2.5	ns
			$5.0 \pm 0.5$	2.5	

**13.6. Timing Requirements**  
 (Unless otherwise specified,  $T_a = -40$  to  $125$  °C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	—	$3.3 \pm 0.3$	5.0	ns
			$5.0 \pm 0.5$	5.0	
Minimum pulse width ( $\overline{\text{CLR}}$ )	$t_{w(L)}$	—	$3.3 \pm 0.3$	5.0	ns
			$5.0 \pm 0.5$	5.0	
Minimum setup time	$t_s$	—	$3.3 \pm 0.3$	6.0	ns
			$5.0 \pm 0.5$	4.5	
Minimum hold time	$t_h$	—	$3.3 \pm 0.3$	0.0	ns
			$5.0 \pm 0.5$	1.0	
Minimum removal time ( $\overline{\text{CLR}}$ )	$t_{rem}$	—	$3.3 \pm 0.3$	3.5	ns
			$5.0 \pm 0.5$	3.0	

**13.7. AC Characteristics** (Unless otherwise specified,  $T_a = 25$  °C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	Note	Test Condition	$V_{CC}$ (V)	$C_L$ (pF)	Min	Typ.	Max	Unit
Propagation delay time (CK-Q)	$t_{PLH}, t_{PHL}$		—	$3.3 \pm 0.3$	15	—	8.4	12.8	ns
					50	—	10.9	16.3	
				$5.0 \pm 0.5$	15	—	5.8	9.0	
					50	—	7.3	11.0	
Propagation delay time ( $\overline{\text{CLR}}$ -Q)	$t_{PHL}$		—	$3.3 \pm 0.3$	15	—	8.3	12.8	ns
					50	—	10.8	16.3	
				$5.0 \pm 0.5$	15	—	5.2	8.6	
					50	—	6.7	10.6	
Maximum clock frequency	$f_{MAX}$		—	$3.3 \pm 0.3$	15	80	125	—	MHz
					50	50	75	—	
				$5.0 \pm 0.5$	15	125	175	—	
					50	85	115	—	
Input capacitance	$C_{IN}$		—			—	4	10	pF
Power dissipation capacitance	$C_{PD}$	(Note 1)	—			—	76	—	pF

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$$

**13.8. AC Characteristics**  
 (Unless otherwise specified,  $T_a = -40$  to  $85$  °C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	$C_L$ (pF)	Min	Max	Unit
Propagation delay time (CK-Q)	$t_{PLH}, t_{PHL}$	—	$3.3 \pm 0.3$	15	1.0	15.0	ns
				50	1.0	18.5	
			$5.0 \pm 0.5$	15	1.0	10.5	
				50	1.0	12.5	
Propagation delay time ( $\overline{\text{CLR}}$ -Q)	$t_{PHL}$	—	$3.3 \pm 0.3$	15	1.0	15.0	ns
				50	1.0	18.5	
			$5.0 \pm 0.5$	15	1.0	10.0	
				50	1.0	12.0	
Maximum clock frequency	$f_{MAX}$	—	$3.3 \pm 0.3$	15	65	—	MHz
				50	45	—	
			$5.0 \pm 0.5$	15	105	—	
				50	75	—	
Input capacitance	$C_{IN}$	—			—	10	pF

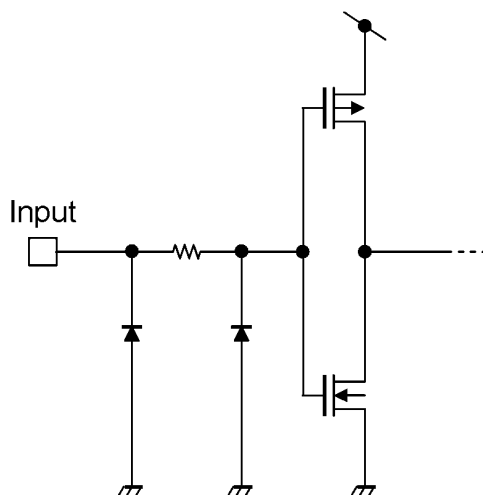
**13.9. AC Characteristics**  
 (Unless otherwise specified,  $T_a = -40$  to  $125$  °C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	$C_L$ (pF)	Min	Max	Unit
Propagation delay time (CK-Q)	$t_{PLH}, t_{PHL}$	—	$3.3 \pm 0.3$	15	1.0	17.0	ns
				50	1.0	20.5	
			$5.0 \pm 0.5$	15	1.0	12.0	
				50	1.0	14.0	
Propagation delay time ( $\overline{\text{CLR}}$ -Q)	$t_{PHL}$	—	$3.3 \pm 0.3$	15	1.0	17.0	ns
				50	1.0	20.5	
			$5.0 \pm 0.5$	15	1.0	11.5	
				50	1.0	13.5	
Maximum clock frequency	$f_{MAX}$	—	$3.3 \pm 0.3$	15	60	—	MHz
				50	40	—	
			$5.0 \pm 0.5$	15	100	—	
				50	65	—	
Input capacitance	$C_{IN}$	—			—	10	pF

**13.10. Noise Characteristics** (Unless otherwise specified,  $T_a = 25$  °C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Typ.	Limit	Unit
Quiet output maximum dynamic $V_{OL}$	$V_{OLP}$	$C_L = 50$ pF	5.0	0.5	0.8	V
Quiet output minimum dynamic $V_{OL}$	$V_{OLV}$	$C_L = 50$ pF	5.0	-0.5	-0.8	V
Minimum high-level dynamic input voltage	$V_{IHD}$	$C_L = 50$ pF	5.0	—	3.5	V
Maximum low-level dynamic input voltage	$V_{ILD}$	$C_L = 50$ pF	5.0	—	1.5	V

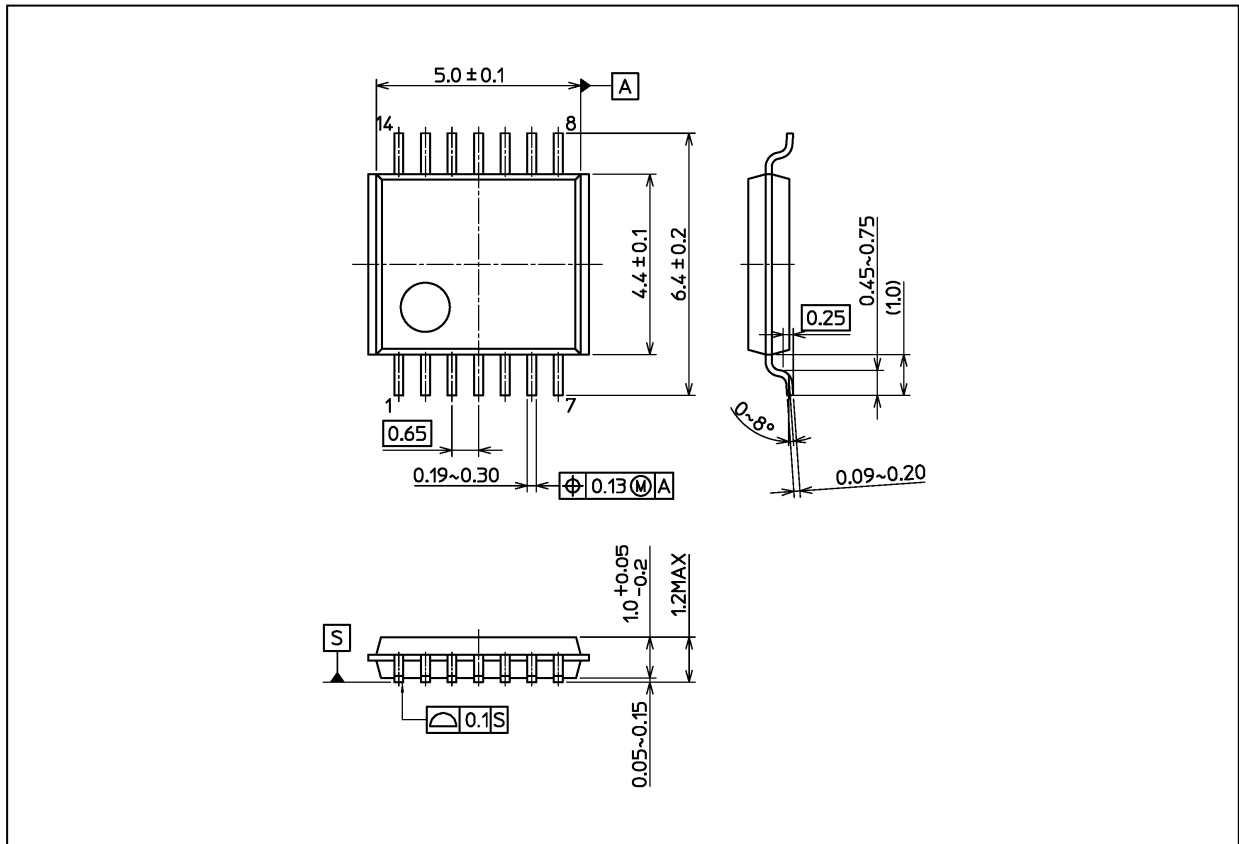
**14. Internal Equivalent Circuit**





Package Dimensions

Unit: mm



Weight: 0.054 g (typ.)

Package Name(s)
Nickname: TSSOP14B

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